

TRANSISTOR MODULE (THREE PHASES BRIDGE TYPE)

QF15AA40/60

TOP

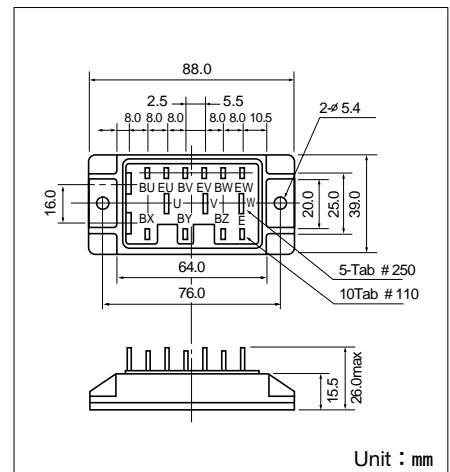
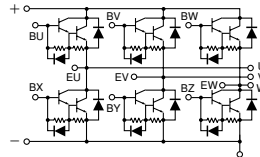


QF15AA is six pack Darlington power transistor module which has six transistors connected in three phase bridge configuration. Each transistor has a reverse paralleled fast recovery diode. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction.

- $I_C=15A$, $V_{CEX}=400/600V$
- Low saturation voltage for higher efficiency.
- High DC current gain h_{FE}
- Isolated mounting base
- $V_{EBO} 10V$ for faster switching speed.

(Applications)

Motor Control (VWF), AC Servo, UPS



Unit : mm

Maximum Ratings

($T_j=25^\circ C$ unless otherwise specified)

Symbol	Item	Conditions	Ratings		Unit
			QF15AA40	QF15AA60	
V_{CBO}	Collector-Base Voltage		400	600	V
V_{CEX}	Collector-Emitter Voltage	$V_{BE}=-2V$	400	600	V
V_{EBO}	Emitter-Base Voltage		10		V
I_C	Collector Current	() = $p_w \leq 1ms$	15 (30)		A
$-I_C$	Reverse Collector Current		15		A
I_B	Base Current		1		A
P_T	Total power dissipation	$T_C=25^\circ C$	100		W
T_j	Junction Temperature		-40 to +150		$^\circ C$
T_{stg}	Storage Temperature		-40 to +125		$^\circ C$
V_{ISO}	Isolation Voltage	A.C.1minute	2500		V
	Mounting Torque (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)		N·m (kgf·cm)
	Mass	Typical Value	95		g

Electrical Characteristics

Symbol	Item	Conditions	Ratings		Unit
			Min.	Max.	
I_{CBO}	Collector Cut-off Current	$V_{CB}=V_{CBO}$		1.0	mA
I_{EBO}	Emitter Cut-off Current	$V_{EB}=V_{EBO}$		100	mA
$V_{CEO(SUS)}$	Collector Emitter Sustaining Voltage	$I_C=1A$	300		V
			450		
$V_{CEX(SUS)}$	Collector Emitter Sustaining Voltage	$I_C=3A, I_{B2}=-1A$	400		V
			600		
h_{FE}	DC Current Gain	$I_C=15A, V_{CE}=2V$	75		
		$I_C=15A, V_{CE}=5V$	100		
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=15A, I_B=0.2A$		2.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C=15A, I_B=0.2A$		2.5	V
t_{on}	Switching Time	$V_{CC}=300V, I_C=15A$ $I_{B1}=0.4A, I_{B2}=-0.4A$		1.0	μs
t_s				12.0	
t_f				2.0	
V_{ECO}	Collector-Emitter Reverse Voltage	$-I_C=15A$		1.5	V
$R_{th(j-c)}$	Thermal Impedance (junction to case)	Transistor part		1.2	$^\circ C/W$
		Diode part		2.5	

